

MOS FIELD EFFECT TRANSISTOR

2SK3431

SWITCHING

N-CHANNEL POWER MOS FET

DESCRIPTION

The 2SK3431 is N-channel MOS Field Effect Transistor designed for high current switching applications.

FEATURES

- Super low on-state resistance:
- $R_{DS(on)1} = 5.6 \text{ m}\Omega \text{ MAX.} (V_{GS} = 10 \text{ V}, \text{ ID} = 42 \text{ A})$
- $R_{\text{DS(on)2}}$ = 8.9 m Ω MAX. (Vgs = 4 V, ID = 42 A)
- Low C_{iss} : $C_{iss} = 6100 \, pF \, TYP$.
- Built-in gate protection diode

ABSOLUTE MAXIMUM RATINGS (TA = 25°C)

Vdss	40	V
Vgss	±20	V
D(DC)	±83	А
D(pulse)	±332	А
Рт	100	W
Рт	1.5	W
Tch	150	°C
Tstg	–55 to +150	°C
AS	65	А
Eas	423	mJ
	VGSS ID(DC) ID(pulse) PT Tch Tstg IAS	VGSS ±20 ID(DC) ±83 ID(pulse) ±332 PT 100 PT 1.5 Tch 150 Tstg -55 to +150 IAS 65

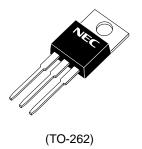
Notes 1. PW \leq 10 μ s, Duty cycle \leq 1%

2. Starting T_{ch} = 25°C, V_{DD} = 20 V, R_G = 25 Ω , V_{GS} = 20 \rightarrow 0 V

ORDERING INFORMATION

PART NUMBER	PACKAGE
2SK3431	TO-220AB
2SK3431-S	TO-262
2SK3431-ZJ	TO-263
2SK3431-Z	TO-220SMD ^{Note}

Note TO-220SMD package is produced only in Japan.





(TO-263, TO-220SMD)



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(TO-220AB)

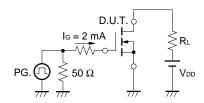
ELECTRICAL CHARACTERISTICS (TA = 25°C)

CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Zero Gate Voltage Drain Current	IDSS	$V_{DS} = 40 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$			10	μA
Gate Leakage Current	lgss	$V_{GS} = \pm 20 V$, $V_{DS} = 0 V$			±10	μA
Gate Cut-off Voltage	V _{GS(off)}	$V_{DS} = 10 V, I_{D} = 1 mA$	1.5	2.0	2.5	V
Forward Transfer Admittance	y _{fs}	V _{DS} = 10 V, I _D = 42 A	30	60		s
Drain to Source On-state Resistance	RDS(on)1	$V_{GS} = 10 V$, $I_D = 42 A$		4.5	5.6	mΩ
	RDS(on)2	Vgs = 4 V, Id = 42 A		6.2	8.9	mΩ
Input Capacitance	Ciss	V _{DS} = 10 V		6100		pF
Output Capacitance	Coss	V _{GS} = 0 V		1400		pF
Reverse Transfer Capacitance	Crss	f = 1 MHz		700		pF
Turn-on Delay Time	td(on)	$V_{DD} = 20 \text{ V}, \text{ I}_{D} = 42 \text{ A}$		120		ns
Rise Time	tr	V _{GS} = 10 V		1800		ns
Turn-off Delay Time	td(off)	R _G = 10 Ω		350		ns
Fall Time	tr			440		ns
Total Gate Charge	Q _G	VDD = 32 V		110		nC
Gate to Source Charge	QGS	V _{GS} = 10 V		18		nC
Gate to Drain Charge	Qgd	ID = 83 A		31		nC
Body Diode Forward Voltage	VF(S-D)	IF = 83 A, VGS = 0 V		1.0		V
Reverse Recovery Time	trr	IF = 83 A, VGS = 0 V		65		ns
Reverse Recovery Charge	Qrr	di/dt = 100 A/µs		110		nC

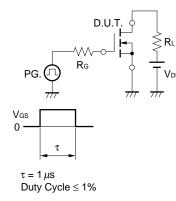
TEST CIRCUIT 1 AVALANCHE CAPABILITY

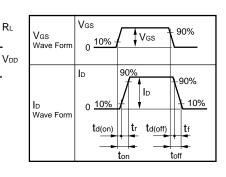
PG. $V_{GS} = 20 \rightarrow 0 V$ V_{TT} V_{DD} V_{DD}

TEST CIRCUIT 3 GATE CHARGE

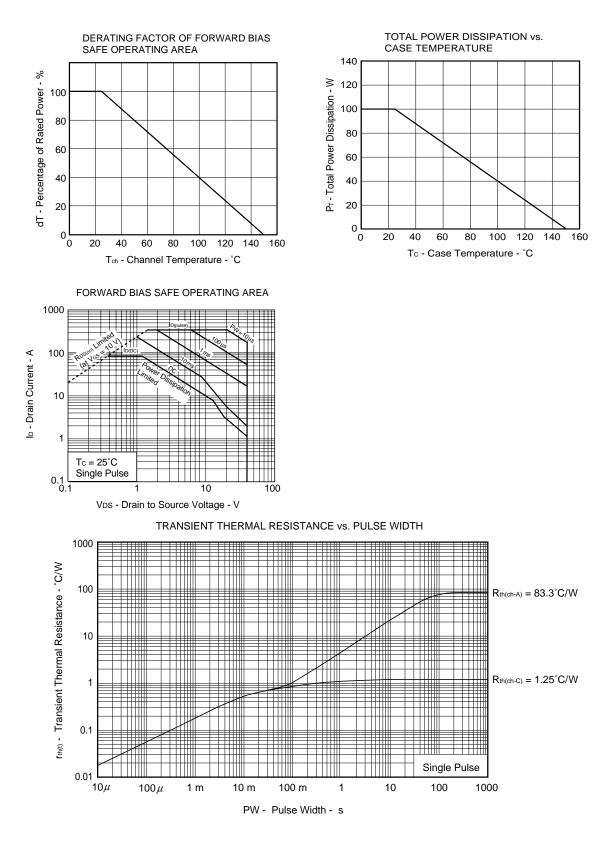


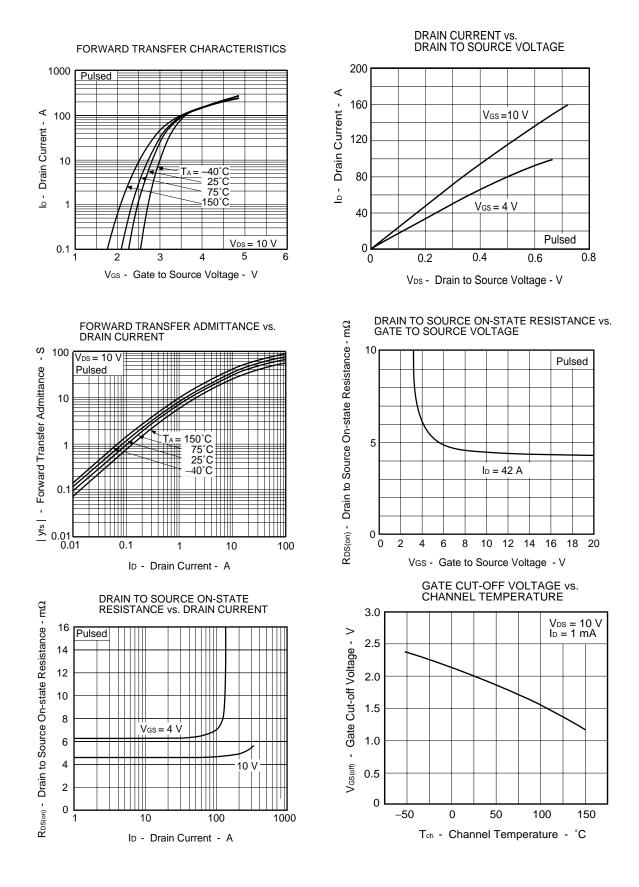
TEST CIRCUIT 2 SWITCHING TIME

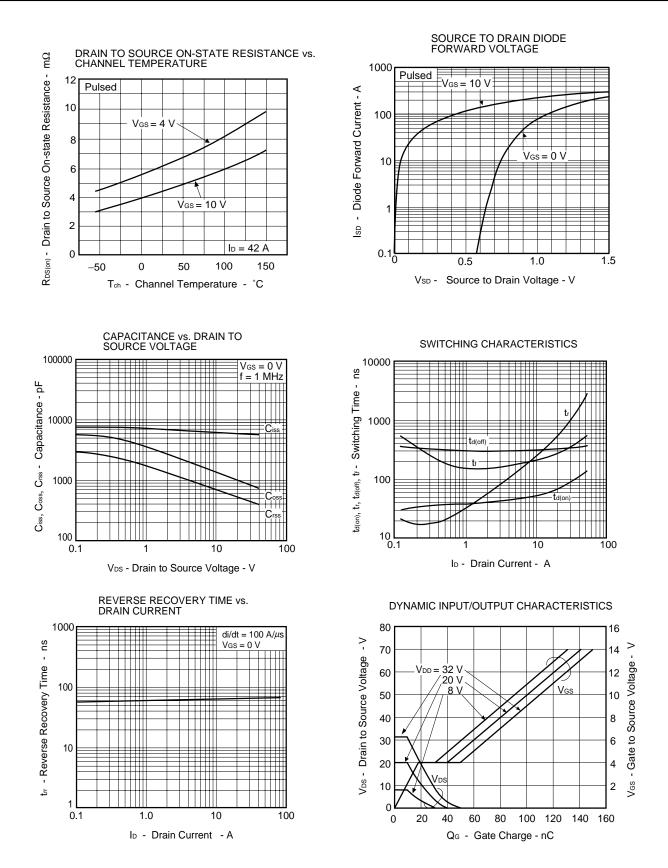


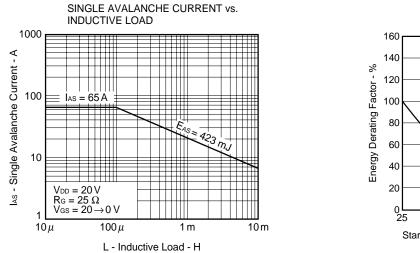


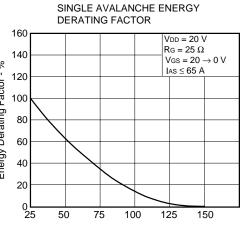
TYPICAL CHARACTERISTICS (TA = 25°C)







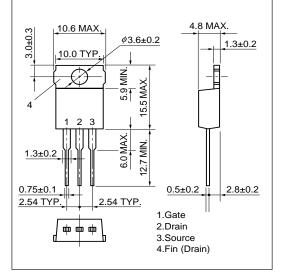




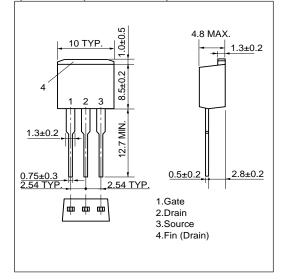
Starting Tch - Starting Channel Temperature - °C

* PACKAGE DRAWINGS (Unit: mm)

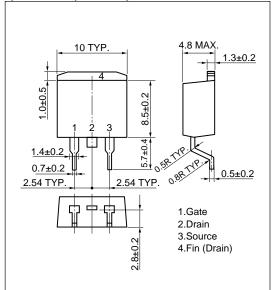
1) TO-220AB (MP-25)



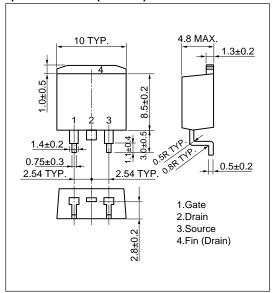
2) TO-262 (MP-25 Fin Cut)



3) TO-263 (MP-25ZJ)

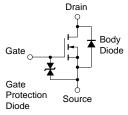


4) TO-220SMD (MP-25Z) Note



Note This package is produced only in Japan.

EQUIVALENT CIRCUIT



Remark

The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

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